

NuPower Xtender™ DUAL-S-50-C01-S01

50 Watt CW 2.2 GHz - 2.5 GHz

P/N: NW-BA-DUAL-S-50-C01-S01

Contact sales@nuwaves.com for custom options, including 3x3 or 4x4 options in a single housing

The NuPower Xtender[™] DUAL-S-50-C01-S01 is a 50W 2x2 dual channel bi-directional amplifier ideal for extending the range of communications and datalinks for ISR applications. This amplifier supports NxN MIMO radios, where 2x2 or 4x4 configurations are used for high data rate applications. This amplifier combines a power amplifier, LNA, and switch, in an integrated microwave assembly for a low SWaP solution to pair with MIMO radios.

Based on highly linear LDMOS technology, this amplifier is perfect for applications requiring both high data rates and high RF output power for long distance data links. It supports complex modulations with high peak-to-average ratios (PARs), where minimal signal distortion is required. Constant envelope signals such as CW, AM, and FM are also supported.

At a nominal +25dBm RF input, the amplifier provides 24dB of gain to achieve a nominal 50 Watts at each of the antenna ports. Each channel is its own independent bi-directional amplifier. The amplifier switches between transmit and receive through a DC control input. Alternatively, the module can be configured for Autosense where it switches between transmit and receive automatically based on the RF input power detected at the XCVR Port.

Extend your operational communication range with NuPower™ amplifiers from NuWaves RF Solutions.

Features

The second secon

X

- 50 Watts (typ) RF Output Power
- 2.2 to 2.5 GHz
- Bidirectional Operation
- 24 dB (typ) of Transmit Gain
- 14.5 dB (typ) Receive Gain
- Integrated Heatsink
- Fast T/R Mode Switching with Auto-Sensing or Manual T/R Line
- Small Form Factor
- Highly Linear LDMOS Technology
- Over-Voltage & Reverse-Voltage Protection

Applications

- Unmanned Aircraft Systems (UAS) -Group 2 and Group 3
- Unmanned Ground Vehicles (UGV)
- Software Defined Radios
- Counter UAS Detection and Mitigation
- MIMO/MANET Radio Range Extension
- SISO Radio Range Extension

Specifications

Absolute Maximums

Per Channel					
Parameter	Rating	Unit			
Max Device Voltage	N/A	V			
Max Device Current	TBD	A			
Max RF Input Power CW,ZL=50 Ω	TBD	dBm			
	TBD				
Max Operating Temperature (ambient)	+71 °C	°C			
Max Operating Temperature (baseplate)	+85 °C	°C			



Electrical Specifications - Operational @ 28 VDC, 25 °C, $Z_S=Z_L=50 \Omega$, CW, Pin = +25 dBm (unless otherwise specified)

Per Channel							
Parameter	Symbol	Min	Тур	Max	Unit	Condition	
RF Output Power, Psat	Psat	45	48		dBm		
Operating Frequency	BW	2200		2500	MHz		
Switching Speed	TX _{ON/OFF}		1.0	2.0	μs		
Operating Voltage	VDC		28		V		
Operating Current (Transmit)	I _{DD}		8	9.5	A		
Module Efficiency (Transmit)			28		%		

Electrical Specifications - Transmit @ 28 VDC, 25 °C, Z_s=Z_L=50 Ω, CW, Pin = +25 dBm (unless otherwise specified)

Per Channel							
Parameter	Symbol	Min	Тур	Мах	Unit	Condition	
RF Output Power, Psat	Psat	45	48		dBm		
Tx Gain	G	20	24		dB		
Power Gain Flatness	ΔG		±1.0		dB	1-2.5 GHz	
Small Signal Gain Flatness	ΔG		TBD		dB	Pin= 0 dBm, 1-2.5 GHz	
Harmonics	2nd		TBD		dBc		
Nominal Input Drive Level	P _{IN}		+25		dBm		
Quescent Current	I _{DQ}		57		mA	T/R Enable Off (Receive Current)	
Tx Current	I _{TX}		8	9.5	A		
Tx Input VSWR (XCVR Port)	VSWR		2:1				
Tx Output Mismatch VSWR	VSWR		10:1 (TBR)		Ψ	No damage at all phase angles	

Specifications (cont.)

Electrical Specifications - Receive @ 28 VDC, 25 °C, Z₃=Z₁=50 Ω, CW, -30 dBm Input Power (unless otherwise specified)

Per Channel							
Parameter	Symbol	Min	Тур	Max	Unit	Condition	
RF Gain	G	12	14.5		dB		
Rx P1dB	P1dB		7.0		dBm		
Rx Gain Flatness	ΔG		±0.5		dB		
Rx Current	I _{RX}		57		mA		
Rx Noise Figure	NF		2.5		dB		
RX Input VSWR (ANT Port)	VSWR		2:1				

Mechanical Specifications

Parameter	Value	Unit	Limits
Dimensions	4.00 x 7.00 x 2.00	in	Max
Weight	TBD	0Z	Max
RF Connectors, Input/Output	TNC/TNC		
Interface Connector	Circular Locking		
Cooling	Adequate Heatsink Required		

Environmental Specifications

Parameter	Symbol	Min	Тур	Max	Unit
Operating Temperature (ambient)	T _A	-40		+71	°C
Operating Temperature (baseplate)	Tc	-40		+85	°C
Storage Temperature	T _{STG}	-55		+85	°C
Altitude	ALT		TBD	50,000	ft
Vibration / Shock Profile TBD			(Profile TBD)		

EVM vs Output Power vs Modulation

Typical Performance Per Channel						
Modulation (802.11g, 20MHz BW, OFDM)	Date Rate	Output Power (W)	EVM (dB)	EVM (%)		
64QAM	54 MBPS	10	≤ -27	≤ 4.46		
16QAM	36 MBPS	20	≤ -21	≤ 8.91		
QPSK	12 MBPS	35	≤ -15	≤ 17.78		
BPSK	9 MBPS	50	≤ -7	≤ 44.66		

Transmit Performance (to be provided soon) Test Conditions: +28 VDC, +25 °C, $Z_5=Z_1=50 \Omega$, CW, +25 dBm Input Power (unless otherwise specified)

Output Power	Output Power - Stepped Input Power
Output Power vs. Input Power	Output Power vs. Input Voltage
Current Consumption	Transmit Small Signal Gain [0dBm Input Power]
Efficiency	Efficiency vs. Output Power

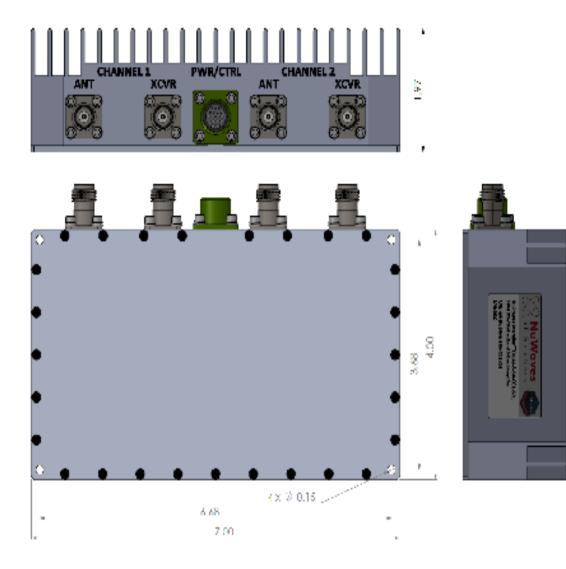
Transmit Performance Plots (cont.) Test Conditions: +28 VDC, +25 °C, $Z_5=Z_1=50 \Omega$, CW, +25 dBm Input Power (unless otherwise specified)

Transmit Input VSWR	Harmonics
Transmit P1dB	EVM vs. Output Power [BPSK (OFDM)]
EVM vs. Output Power [QPSK (OFDM)]	EVM vs. Output Power [16QAM (OFDM)]
EVM vs. Output Power [QPSK (OFDM)]	EVM vs. Output Power [16QAM (OFDM)]
EVM vs. Output Power [QPSK (OFDM)]	EVM vs. Output Power [16QAM (OFDM)]
EVM vs. Output Power [QPSK (OFDM)]	EVM vs. Output Power [16QAM (OFDM)]
EVM vs. Output Power [QPSK (OFDM)]	EVM vs. Output Power [16QAM (OFDM)]
EVM vs. Output Power [QPSK (OFDM)]	EVM vs. Output Power [16QAM (OFDM)]
EVM vs. Output Power [QPSK (OFDM)]	EVM vs. Output Power [16QAM (OFDM)]
EVM vs. Output Power [QPSK (OFDM)]	EVM vs. Output Power [16QAM (OFDM)]
	EVM vs. Output Power [16QAM (OFDM)]
EVM vs. Output Power [QPSK (OFDM)] EVM vs. Output Power [64QAM (OFDM)]	EVM vs. Output Power [16QAM (OFDM)]
	EVM vs. Output Power [16QAM (OFDM)]
	EVM vs. Output Power [16QAM (OFDM)]
	EVM vs. Output Power [16QAM (OFDM)]
	EVM vs. Output Power [16QAM (OFDM)]
	EVM vs. Output Power [16QAM (OFDM)]

Receive Performance Plots (to be provided soon) Test Conditions: +28 VDC, +25 °C, Z_S=Z_L=50 Ω, CW, -30 dBm Input Power (unless otherwise specified)

Receive Gain vs Temperature Receive Gain Receive P1dB **Receive Noise Figure** Receive Input VSWR Receive Noise Figure vs Temperature

Mechanical Outline



Accessory Part Numbers - Sold Separately

Part Number	Description
<u>NW-FL-05LPLE-2500-</u> <u>SFSF-M01</u>	Harmonic Filter Module
TBD	Standard Interface Cable Assembly – Flying Leads
TBD	Upgraded Interface Cable Assembly – Banana Plug Termination

For information on product disposal (end-of-life), please refer to this document: https://nuwaves.com/wp-content/uploads/Product-Disposal-End-of-Life.pdf

Pinout

Function	I/O	Pin	Logic Voltage
DC Power (Primary Power, +11 to +32 Volts)		TBD	_
Ground (DC Return)		TBD	-
Over Temperature Flag		TBD	_
T/R Enable			TBD
T/R Mode: Source (Autosense) ¹ T/R Mode: Sink (Manual T/R) [High TX / Low RX]	1/0	TBD	TBD

¹Autosense automatically switches to transmit and receive based on input signal strength. Typical threshold is TBD; see user manual for complete information.



Contact NuWaves



NuWaves RF Solutions 132 Edison Drive Middletown, OH 45044 www.nuwaves.com sales@nuwaves.com 513.360.0800



Rev 110424 ©2024 NuWaves Ltd. Specifications subject to change without notice. Export of NuWaves Ltd. products are subject to U.S. export controls. U.S. export licenses may be required.